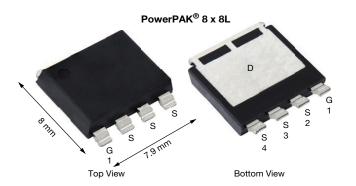


www.vishay.com

Vishay Siliconix

Automotive N-Channel 40 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY					
V _{DS} (V)	40				
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	0.0009				
I _D (A)	575				
Configuration	Single				
Package	PowerPAK 8 x 8L				

FEATURES

- TrenchFET® Gen IV power MOSFET
- AEC-Q101 qualified
- 100 % R_q and UIS tested
- Thin 1.6 mm package
- · Very low thermal resistance
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



G 0 –	

N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS	(T _C = 25 °C, unles	s otherwise noted)		
PARAMETER	SYMBOL	LIMIT	UNIT		
Drain-source voltage		V _{DS}	40	V	
Gate-source voltage		V_{GS}	± 20		
Continuous drain current	T _C = 25 °C	- I _D	575		
	T _C = 125 °C		330		
Continuous source current (diode conduction)	I _S	545	Α		
Pulsed drain current ^a		I _{DM}	1800		
Single pulse avalanche current	L = 0.1 mH	I _{AS}	60		
Single pulse avalanche energy	L = U.1 IIII	E _{AS}	180	mJ	
Maximum power dissipation	T _C = 25 °C	В	600	W	
	T _C = 125 °C	- P _D	200	VV	
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°C	
Soldering recommendations (peak temperature) c			260		

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-ambient	PCB mount ^b	R_{thJA}	44	°C/W	
Junction-to-case (drain)		R_{thJC}	0.25	- C/VV	

Notes

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %
- b. When mounted on 1" square PCB (FR4 material)
- c. See solder profile (www.vishay.com/doc?73257). The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection



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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static							
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0, I_D = 250 \mu A$		40	-	-	V
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	= V _{GS} , I _D = 250 μA	2	3	3.5	V
Gate-source leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$		-	-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = 40 V	-	-	1	
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	$V_{DS} = 40 \text{ V}, T_{J} = 125 ^{\circ}\text{C}$	-	-	50	μA
		V _{GS} = 0 V	V _{DS} = 40 V, T _J = 175 °C	-	-	150	
On-state drain current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	100	-	-	Α
		V _{GS} = 10 V	I _D = 20 A	-	0.0007	0.0009	Ω
Drain-source on-state resistance a	R _{DS(on)}	V _{GS} = 10 V	I _D = 20 A, T _J = 125 °C	-	-	0.0015	
		V _{GS} = 10 V	I _D = 20 A, T _J = 175 °C	-	-	0.0019	
Forward transconductance b	9 _{fs}	V_{DS}	= 15 V, I _D = 60 A	-	160	-	S
Dynamic ^b							
Input capacitance	C _{iss}		V _{DS} = 25 V, f = 1 MHz	-	7220	9020	
Output capacitance	C _{oss}	$V_{GS} = 0 V$		-	2290	2860	pF
Reverse transfer capacitance	C _{rss}			-	175	220	
Total gate charge ^c	Qg		V _{DS} = 20 V, I _D = 30 A	-	116	145	nC
Gate-source charge ^c	Q _{gs}	V _{GS} = 10 V		-	36	-	
Gate-drain charge ^c	Q _{gd}				25	-	1
Gate resistance	Rg		f = 1 MHz		1.6	2.6	Ω
Turn-on delay time ^c	t _{d(on)}	$V_{DD} = 20 \text{ V}, \text{ R}_L = 0.66 \Omega$ $I_D \cong 30 \text{ A}, V_{GEN} = 10 \text{ V}, \text{ R}_g = 1 \Omega$		-	17	27	- ns
Rise time ^c	t _r			-	27	41	
Turn-off delay time ^c	t _{d(off)}			-	41	62	
Fall time ^c	t _f			-	18	27	
Source-Drain Diode Ratings and Cha	aracteristics ^b						
Reverse recovery time	t _{rr}	V _{DD} = 32 V, I _{FM} = 15 A, di/dt = 100 A/μs		-	66	-	ns
Reverse recovery charge	Q _{rr}				94	-	nC
Reverse recovery current	I _{RM}			-	-	-3.6	Α
Pulsed current ^a	I _{SM}			-	-	1600	Α
Forward voltage	V _{SD}	I _F = 50 A, V _{GS} = 0		-	0.8	1.1	V

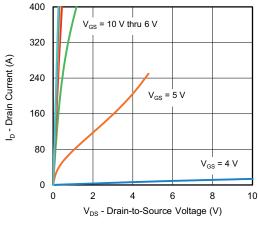
Notes

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

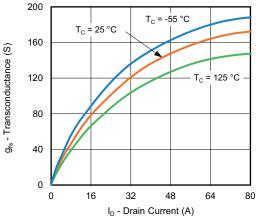
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



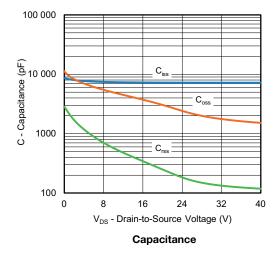
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

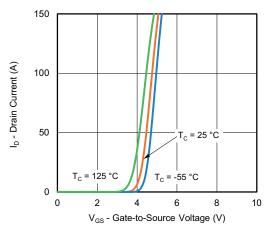


Output Characteristics

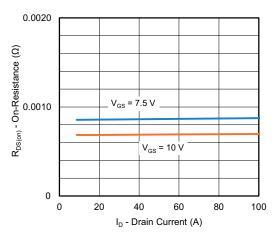


Transconductance

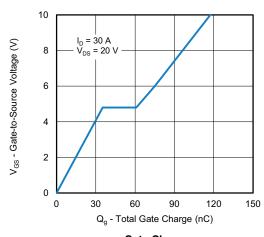




Transfer Characteristics

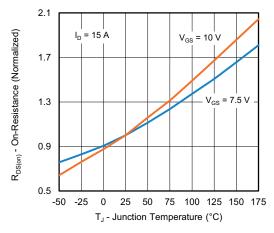


On-Resistance vs. Drain Current

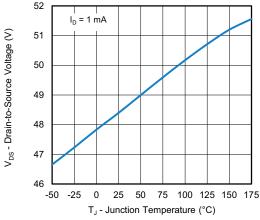




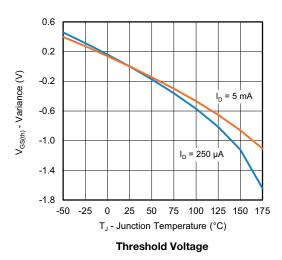
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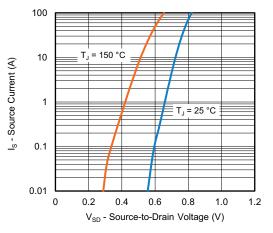


On-Resistance vs. Junction Temperature

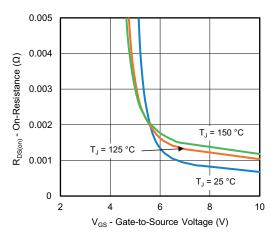


Drain Source Breakdown vs. Junction Temperature

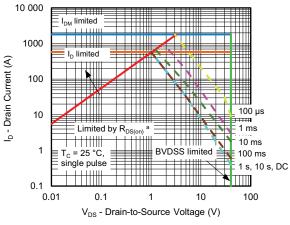




Source Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage



Safe Operating Area

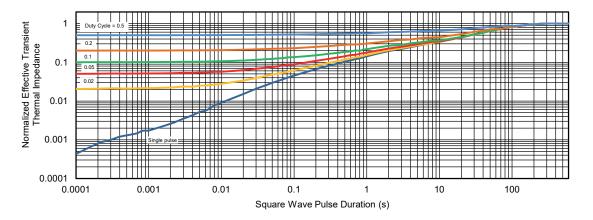
Note

a. V_{GS} > minimum V_{GS} at which R_{DS(on)} is specified

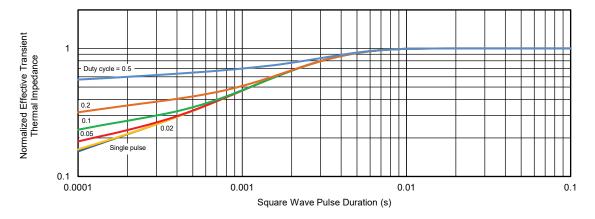
For technical questions, contact: automostech



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient

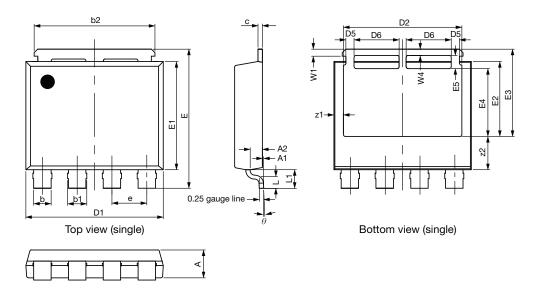


Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?77170.



PowerPAK® 8 x 8L BWL Case Outline 2



MAX.
0.067
0.005
0.030
0.043
0.046
0.277
0.012
0.315
0.272
0.022
0.106
0.080
0.319
0.249
0.174
0.202
0.157
0.033
0.030
0.045
0.020
0.017
0.026
0.079
5°

ECN: S19-0643-Rev. B, 05-Aug-2019

DWG: 6073

Note

Millimeter will govern



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